

# Complementary Darlington Power Transistor

DPAK For Surface Mount Applications

## MJD122, NJVMJD122 (NPN), MJD127, NJVMJD127 (PNP)

Designed for general purpose amplifier and low speed switching applications.

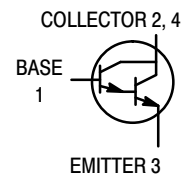
### Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves
- Surface Mount Replacements for 2N6040–2N6045 Series, TIP120–TIP122 Series, and TIP125–TIP127 Series
- Monolithic Construction With Built-in Base-Emitter Shunt Resistors
- High DC Current Gain:  $h_{FE} = 2500$  (Typ) @  $I_C = 4.0$  Adc
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings:
  - ♦ Human Body Model,  $3B > 8000$  V
  - ♦ Machine Model,  $C > 400$  V
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

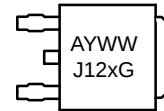
SILICON  
POWER TRANSISTOR  
8 AMPERES  
100 VOLTS, 20 WATTS



DPAK  
CASE 369C  
STYLE 1



### MARKING DIAGRAM



|    |                     |
|----|---------------------|
| A  | = Assembly Location |
| Y  | = Year              |
| WW | = Work Week         |
| x  | = 2 or 7            |
| G  | = Pb-Free Package   |

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

## MJD122, NJVMJD122 (NPN), MJD127, NJVMJD127 (PNP)

### MAXIMUM RATINGS

| Rating                                                                                                                | Symbol         | Value         | Unit                       |
|-----------------------------------------------------------------------------------------------------------------------|----------------|---------------|----------------------------|
| Collector-Emitter Voltage                                                                                             | $V_{CEO}$      | 100           | Vdc                        |
| Collector-Base Voltage                                                                                                | $V_{CB}$       | 100           | Vdc                        |
| Emitter-Base Voltage                                                                                                  | $V_{EB}$       | 5             | Vdc                        |
| Collector Current<br>Continuous<br>Peak                                                                               | $I_C$          | 8<br>16       | Adc                        |
| Base Current                                                                                                          | $I_B$          | 120           | mAdc                       |
| Total Power Dissipation<br>@ $T_C = 25\text{ }^{\circ}\text{C}$<br>Derate above $25\text{ }^{\circ}\text{C}$          | $P_D$          | 20<br>0.16    | W<br>W/ $^{\circ}\text{C}$ |
| Total Power Dissipation (Note 1)<br>@ $T_A = 25\text{ }^{\circ}\text{C}$<br>Derate above $25\text{ }^{\circ}\text{C}$ | $P_D$          | 1.75<br>0.014 | W<br>W/ $^{\circ}\text{C}$ |
| Operating and Storage Junction Temperature Range                                                                      | $T_J, T_{stg}$ | -65 to +150   | $^{\circ}\text{C}$         |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS

| Characteristic                                   | Symbol          | Max  | Unit                 |
|--------------------------------------------------|-----------------|------|----------------------|
| Thermal Resistance, Junction-to-Case             | $R_{\theta JC}$ | 6.25 | $^{\circ}\text{C/W}$ |
| Thermal Resistance, Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 71.4 | $^{\circ}\text{C/W}$ |

1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

# MJD122, NJVMJD122 (NPN), MJD127, NJVMJD127 (PNP)

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

### OFF CHARACTERISTICS

|                                                                                |               |     |    |                 |
|--------------------------------------------------------------------------------|---------------|-----|----|-----------------|
| Collector-Emitter Sustaining Voltage<br>( $I_C = 30\text{ mAdc}$ , $I_B = 0$ ) | $V_{CE(sus)}$ | 100 | –  | Vdc             |
| Collector Cutoff Current<br>( $V_{CE} = 50\text{ Vdc}$ , $I_B = 0$ )           | $I_{CEO}$     | –   | 10 | $\mu\text{Adc}$ |
| Collector Cutoff Current<br>( $V_{CB} = 100\text{ Vdc}$ , $I_E = 0$ )          | $I_{CBO}$     | –   | 10 | $\mu\text{Adc}$ |
| Emitter Cutoff Current<br>( $V_{BE} = 5\text{ Vdc}$ , $I_C = 0$ )              | $I_{EBO}$     | –   | 2  | mAdc            |

### ON CHARACTERISTICS

|                                                                                                                                                |               |             |             |     |
|------------------------------------------------------------------------------------------------------------------------------------------------|---------------|-------------|-------------|-----|
| DC Current Gain<br>( $I_C = 4\text{ Adc}$ , $V_{CE} = 4\text{ Vdc}$ )<br>( $I_C = 8\text{ Adc}$ , $V_{CE} = 4\text{ Vdc}$ )                    | $h_{FE}$      | 1000<br>100 | 12,000<br>– | –   |
| Collector-Emitter Saturation Voltage<br>( $I_C = 4\text{ Adc}$ , $I_B = 16\text{ mAdc}$ )<br>( $I_C = 8\text{ Adc}$ , $I_B = 80\text{ mAdc}$ ) | $V_{CE(sat)}$ | –<br>–      | 2<br>4      | Vdc |
| Base-Emitter Saturation Voltage (Note 2)<br>( $I_C = 8\text{ Adc}$ , $I_B = 80\text{ mAdc}$ )                                                  | $V_{BE(sat)}$ | –           | 4.5         | Vdc |
| Base-Emitter On Voltage<br>( $I_C = 4\text{ Adc}$ , $V_{CE} = 4\text{ Vdc}$ )                                                                  | $V_{BE(on)}$  | –           | 2.8         | Vdc |

### DYNAMIC CHARACTERISTICS

|                                                                                                                                 |            |        |            |     |
|---------------------------------------------------------------------------------------------------------------------------------|------------|--------|------------|-----|
| Current-Gain-Bandwidth Product<br>( $I_C = 3\text{ Adc}$ , $V_{CE} = 4\text{ Vdc}$ , $f = 1\text{ MHz}$ )                       | $ h_{fe} $ | 4      | –          | MHz |
| Output Capacitance<br>( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f = 0.1\text{ MHz}$ )<br>MJD127, NJVMJD127<br>MJD122, NJVMJD122 | $C_{ob}$   | –<br>– | 300<br>200 | pF  |
| Small-Signal Current Gain<br>( $I_C = 3\text{ Adc}$ , $V_{CE} = 4\text{ Vdc}$ , $f = 1\text{ kHz}$ )                            | $h_{fe}$   | 300    | –          | –   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

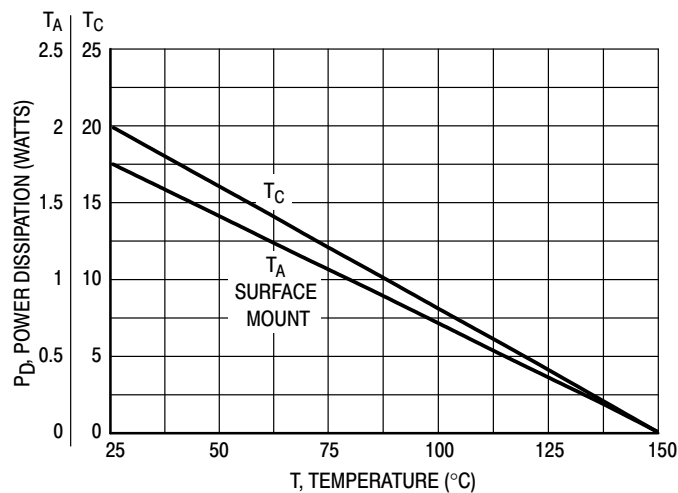


Figure 1. Power Derating

# MJD122, NJVMJD122 (NPN), MJD127, NJVMJD127 (PNP)

## TYPICAL ELECTRICAL CHARACTERISTICS

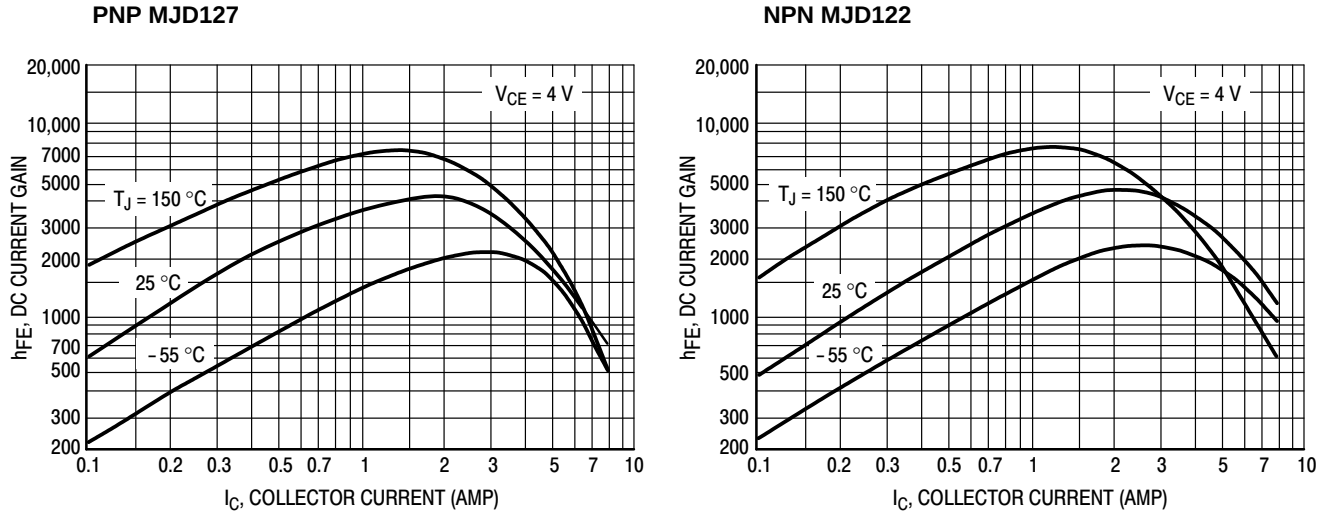


Figure 2. DC Current Gain

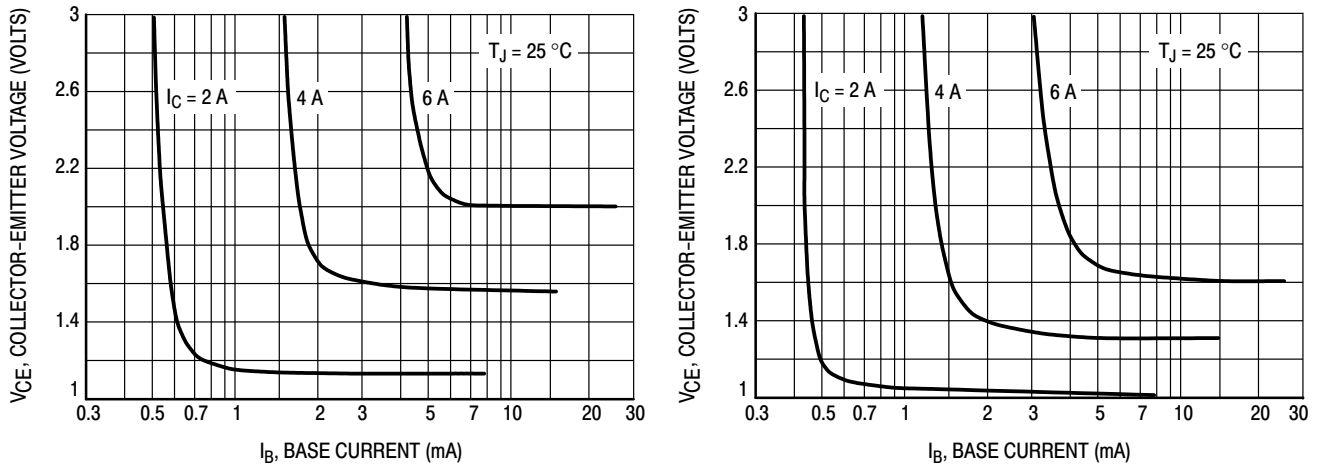


Figure 3. Collector Saturation Region

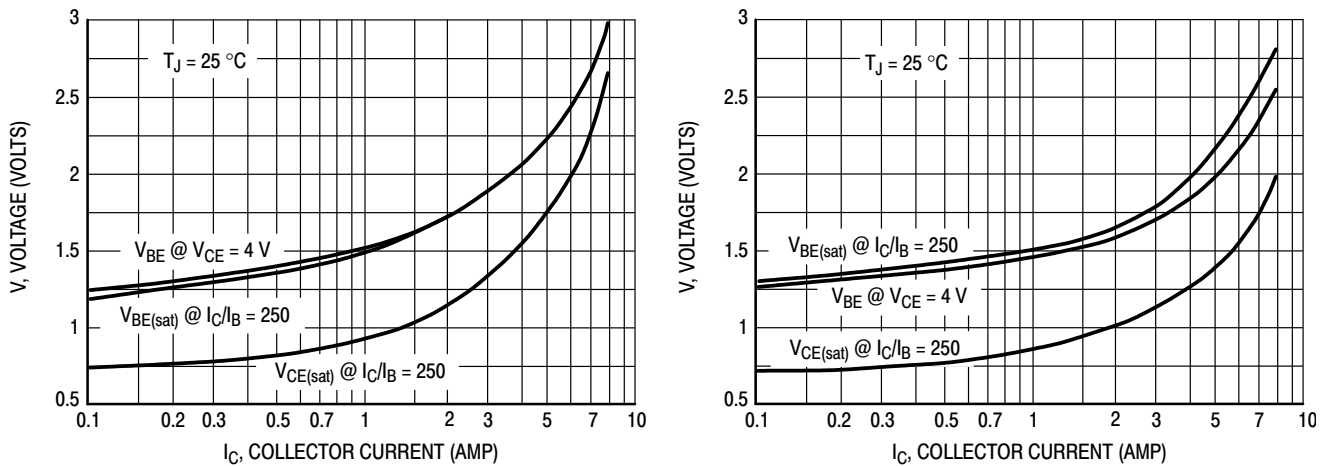


Figure 4. "On" Voltages

TYPICAL ELECTRICAL CHARACTERISTICS

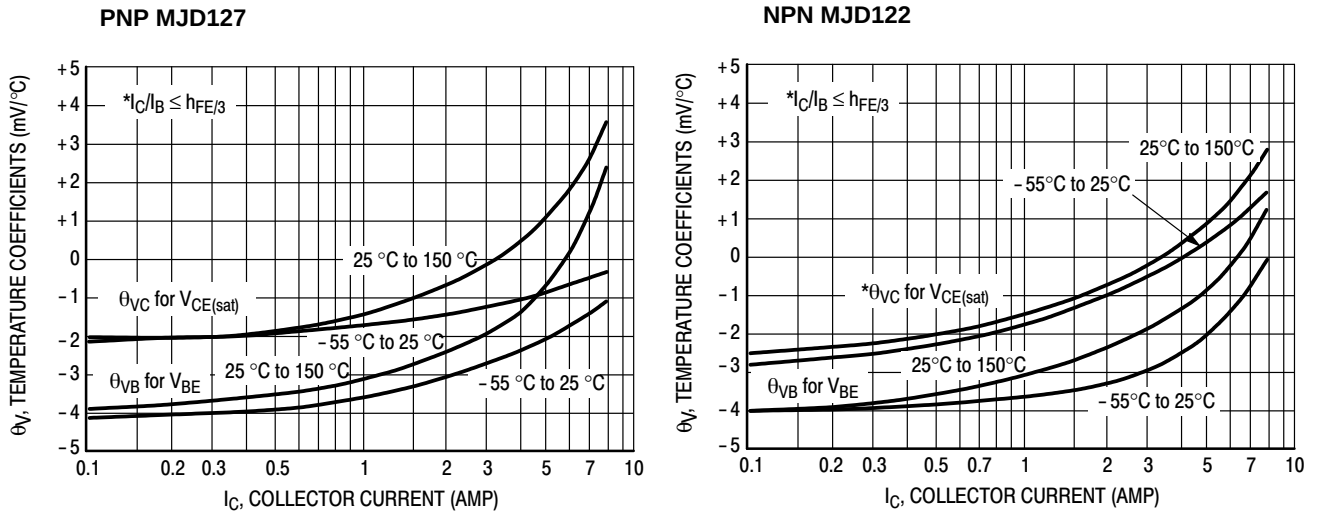


Figure 5. Temperature Coefficients

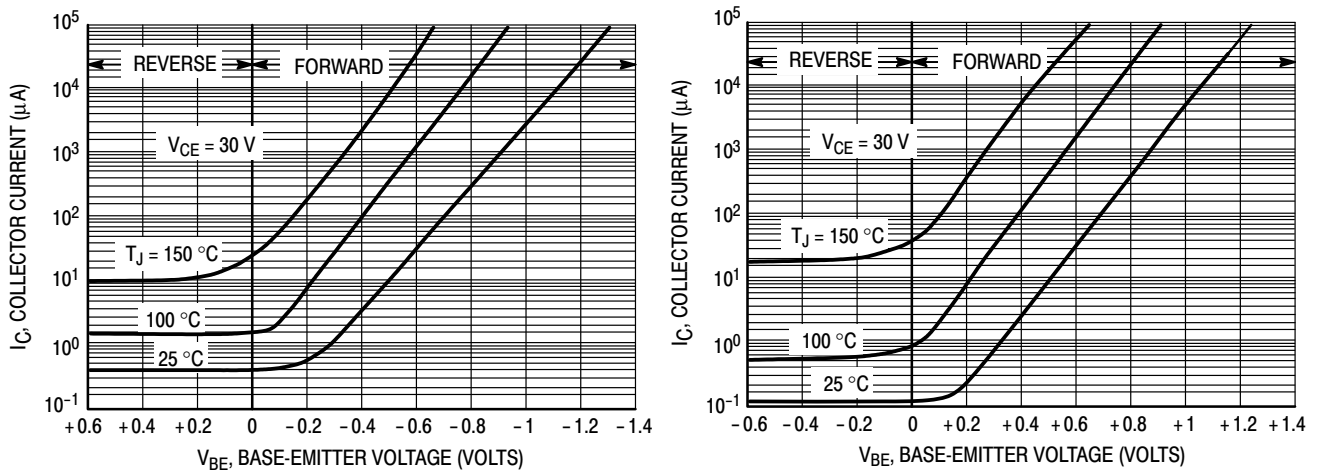


Figure 6. Collector Cut-Off Region

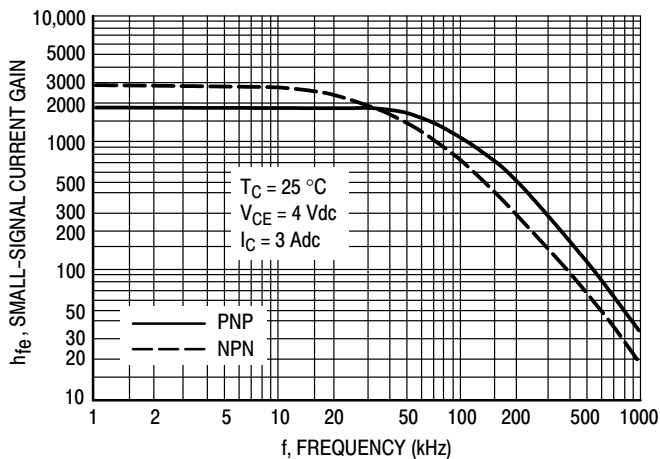


Figure 7. Small-Signal Current Gain

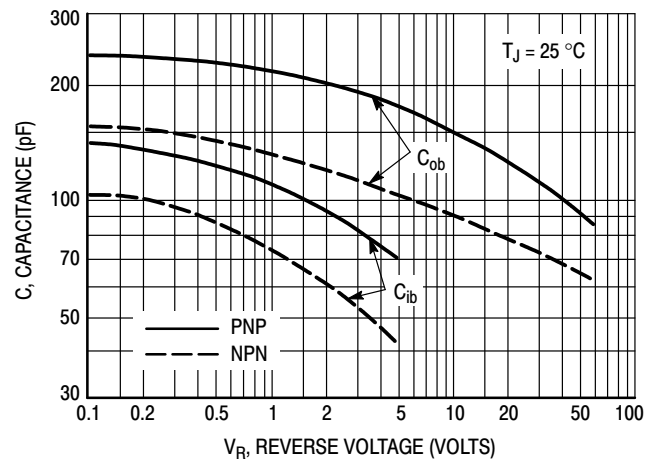


Figure 8. Capacitance

## MJD122, NJVMJD122 (NPN), MJD127, NJVMJD127 (PNP)

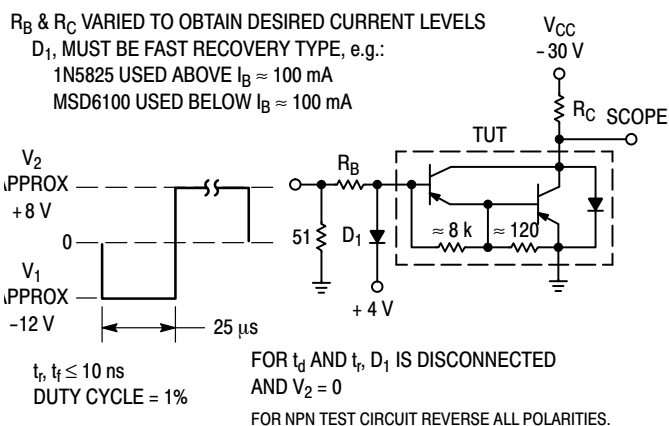


Figure 9. Switching Times Test Circuit

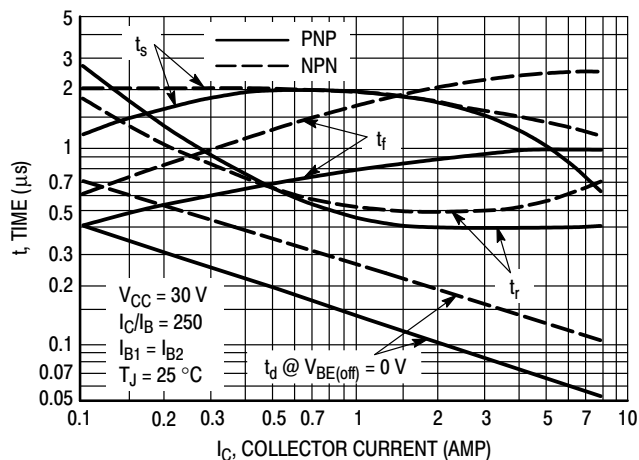


Figure 10. Switching Times

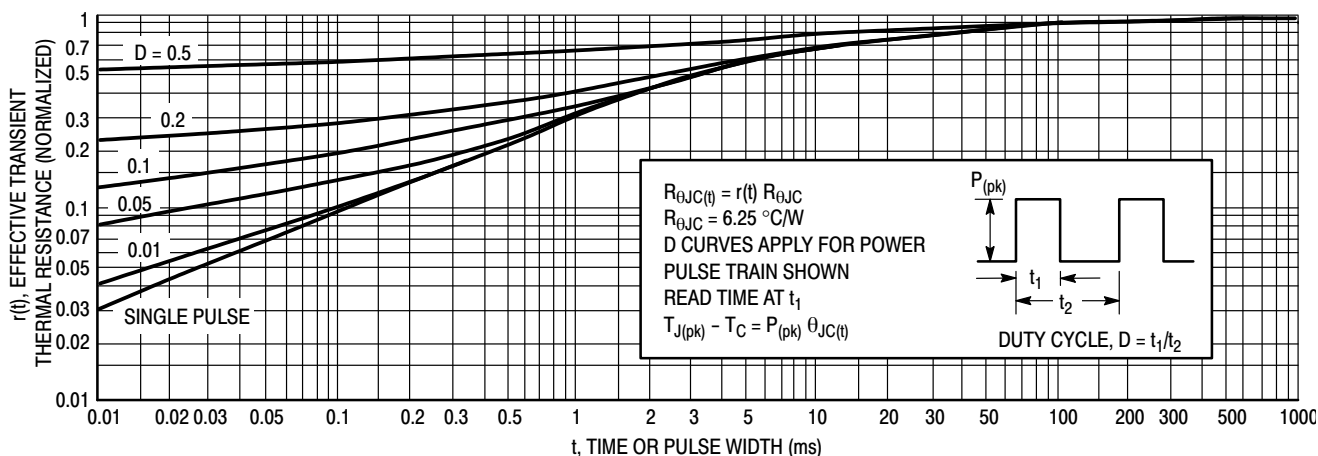


Figure 11. Thermal Response

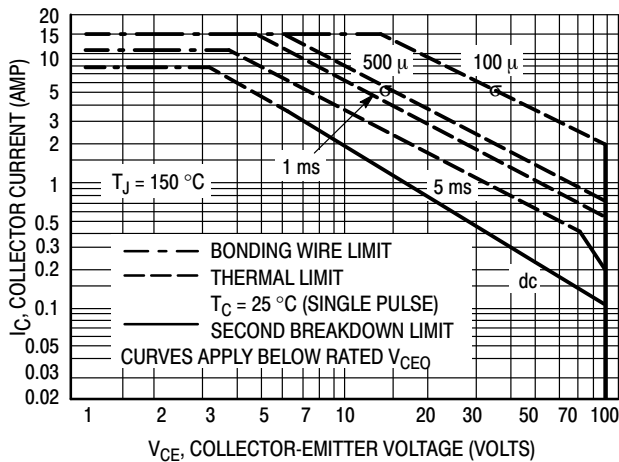


Figure 12. Maximum Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 12 is based on  $T_{J(pk)} = 150^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} < 150^\circ\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 11. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

## MJD122, NJVMJD122 (NPN), MJD127, NJVMJD127 (PNP)

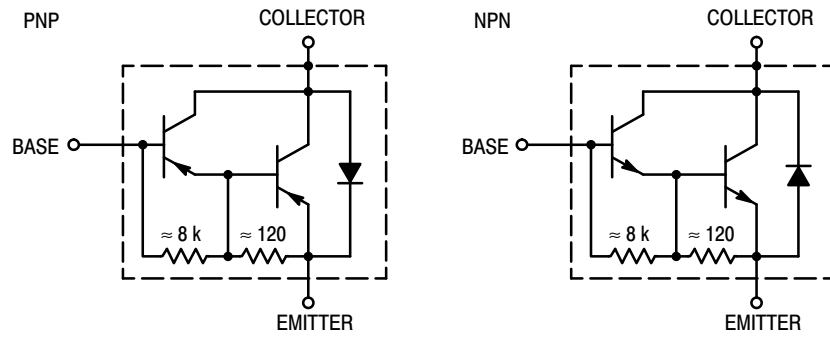


Figure 13. Darlington Schematic

### ORDERING INFORMATION

| Device        | Package Type      | Shipping <sup>†</sup> |
|---------------|-------------------|-----------------------|
| MJD122G       | DPAK<br>(Pb-Free) | 75 Units / Rail       |
| MJD122T4G     | DPAK<br>(Pb-Free) | 2,500 / Tape & Reel   |
| NJVMJD122T4G* | DPAK<br>(Pb-Free) | 2,500 / Tape & Reel   |
| MJD127G       | DPAK<br>(Pb-Free) | 75 Units / Rail       |
| MJD127T4G     | DPAK<br>(Pb-Free) | 2,500 / Tape & Reel   |
| NJVMJD127T4G* | DPAK<br>(Pb-Free) | 2,500 / Tape & Reel   |

<sup>†</sup> For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

\* NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

## MJD122, NJVMJD122 (NPN), MJD127, NJVMJD127 (PNP)

### REVISION HISTORY

| Revision | Description of Changes                          | Date     |
|----------|-------------------------------------------------|----------|
| 16       | Rebranded the document to <b>onsemi</b> format. | 4/1/2026 |

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

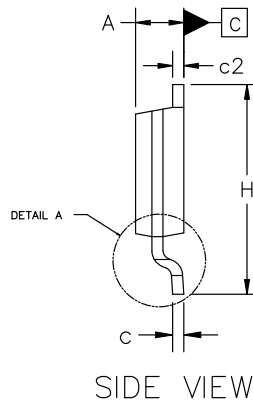
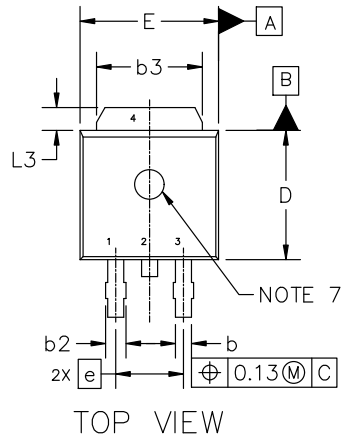




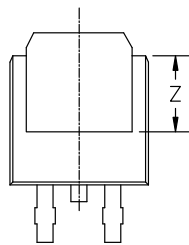
**DPAK-3 6.10x6.54x2.28, 2.29P**  
**CASE 369C**  
**ISSUE K**

DATE 14 MAY 2026

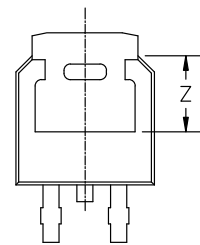
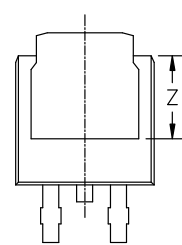
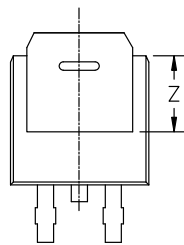
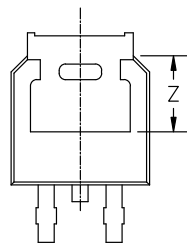
SCALE 1:1



| MILLIMETERS |          |      |       |
|-------------|----------|------|-------|
| DIM         | MIN      | NOM  | MAX   |
| A           | 2.18     | 2.28 | 2.38  |
| A1          | 0.00     | ---  | 0.13  |
| b           | 0.63     | 0.76 | 0.89  |
| b2          | 0.72     | 0.93 | 1.14  |
| b3          | 4.57     | 5.02 | 5.46  |
| c           | 0.46     | 0.54 | 0.61  |
| c2          | 0.46     | 0.54 | 0.61  |
| D           | 5.97     | 6.10 | 6.22  |
| E           | 6.35     | 6.54 | 6.73  |
| e           | 2.29 BSC |      |       |
| H           | 9.40     | 9.91 | 10.41 |
| L           | 1.40     | 1.59 | 1.78  |
| L1          | 2.90 REF |      |       |
| L2          | 0.51 BSC |      |       |
| L3          | 0.89     | ---  | 1.27  |
| L4          | ---      | ---  | 1.01  |
| Z           | 3.93     | ---  | ---   |



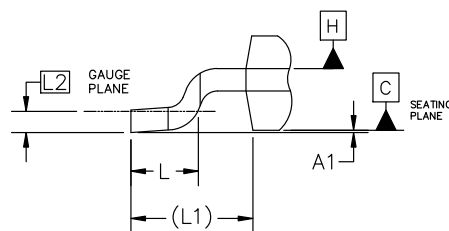
BOTTOM VIEW



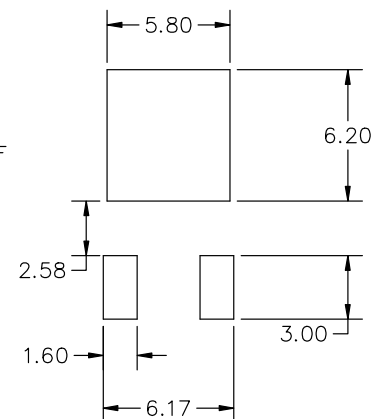
ALTERNATE CONSTRUCTIONS

NOTES:

1. DIMENSIONING AND TOLERANCING ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3, AND Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
7. OPTIONAL MOLD FEATURE.



DETAIL A  
ROTATED 90° CW



RECOMMENDED MOUNTING FOOTPRINT\*

\*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

|                         |                                     |                                                                                                                                                                                  |
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**DPAK–3 6.10x6.54x2.28, 2.29P
 CASE 369C
 ISSUE K**

DATE 13 MAY 2026

**GENERIC  
MARKING DIAGRAM\***



XXXXXX = Device Code  
 A = Assembly Location  
 L = Wafer Lot  
 Y = Year  
 WW = Work Week  
 G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

|                                                                              |                                                                              |                                                                         |                                                                                   |                                                                          |
|------------------------------------------------------------------------------|------------------------------------------------------------------------------|-------------------------------------------------------------------------|-----------------------------------------------------------------------------------|--------------------------------------------------------------------------|
| <b>STYLE 1:</b><br>PIN 1. BASE<br>2. COLLECTOR<br>3. EMITTER<br>4. COLLECTOR | <b>STYLE 2:</b><br>PIN 1. GATE<br>2. DRAIN<br>3. SOURCE<br>4. DRAIN          | <b>STYLE 3:</b><br>PIN 1. ANODE<br>2. CATHODE<br>3. ANODE<br>4. CATHODE | <b>STYLE 4:</b><br>PIN 1. CATHODE<br>2. ANODE<br>3. GATE<br>4. ANODE              | <b>STYLE 5:</b><br>PIN 1. GATE<br>2. ANODE<br>3. CATHODE<br>4. ANODE     |
| <b>STYLE 6:</b><br>PIN 1. MT1<br>2. MT2<br>3. GATE<br>4. MT2                 | <b>STYLE 7:</b><br>PIN 1. GATE<br>2. COLLECTOR<br>3. EMITTER<br>4. COLLECTOR | <b>STYLE 8:</b><br>PIN 1. N/C<br>2. CATHODE<br>3. ANODE<br>4. CATHODE   | <b>STYLE 9:</b><br>PIN 1. ANODE<br>2. CATHODE<br>3. RESISTOR ADJUST<br>4. CATHODE | <b>STYLE 10:</b><br>PIN 1. CATHODE<br>2. ANODE<br>3. CATHODE<br>4. ANODE |

|                         |                                     |                                                                                                                                                                                     |
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| <b>DESCRIPTION:</b>     | <b>DPAK–3 6.10x6.54x2.28, 2.29P</b> | <b>PAGE 2 OF 2</b>                                                                                                                                                                  |

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